



NPN transistor power module

General features

- NPN Transistor
- High current power bipolar module
- Very low R_{th} junction case
- Specific accidental overload areas
- Fully insulated package (U.L. compliant) for easy mounting
- Low internal parasitic inductance
- In compliance with the 2002/93/EC European Directive

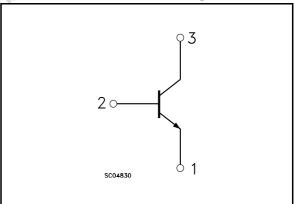
Pin 4 not connected ISOTOP

Applications

- Motor control
- SMPS & UPS
- Welding equipment

 Welding equipment

Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing
BUV298V	BUV298V	ISOTOP	Tube

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BUV298V Electrical ratings

1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CEV}	Collector-emitter voltage (V _{BE} = -5V)	850	V
V _{CEO(sus)}	Collector-emitter voltage (I _B = 0)	450	V
V _{EBO}	Emitter-base voltage ($I_C = 0$)	7	V
Ic	Collector current	50	Α
I _{CM}	Collector peak current (t _P < 10ms)	75	А
I _B	Base current	10	Α
I _{BM}	Base peak current (t _P < 10ms)	16	Α
P _{tot}	Total dissipation at T _c = 25°C	250	W
V _{isol}	Insulation insulation withstand voltage (RMS) from all four leads to external heatsink	2500	٧
T _{stg}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

Table 2. Thermal data

Syr	mbol	Parameter		Value	Unit
R _{thj}	ij-case Thermal r	resistance junction-case	max	0.5	°C/W
R _t	thc-h Thermal rapplied	esistance case heatsink with condu	nctive grease max	0.05	°C/W
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Electrical characteristics BUV298V

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 3. Electrical characteristics

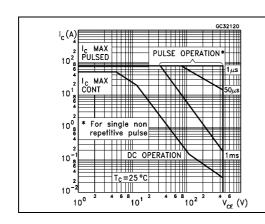
	Symbol	Parameter Test Conditions		Min.	Тур.	Max.	Unit
	Syllibol	Parameter		WIIII.	Typ.	wax.	Unit
	I _{CER}	Collector cut-off current ($R_{BE} = 5\Omega$)	$V_{CE} = V_{CEV}$ $V_{CE} = V_{CEV}$ $T_j = 100^{\circ}C$			0.4 2	mA mA
	I _{CEV}	Collector cut-off current (V _{BE} =-5V)	$V_{CE} = V_{CEV}$ $V_{CE} = V_{CEV}$ $T_j = 100^{\circ}C$			0.4	mA mA
	I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} =5V			2	mA
	V _{CEO(sus)} (1)	Collector-emitter sustaining voltage $(I_B = 0)$	$I_C = 0.2A$ L = 25mH $V_{clamp} = 450V$	450	0		V
	h _{FE}	DC current gain	$I_C = 32A$ $V_{CE} = 5V$		12		
	V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = 32A$ $I_B = 6.4A$ $I_C = 32A$ $I_B = 6.4A$ $T_j = 100$ °C		0.35 0.6	1.2 2	V V
	V _{BE(sat)} (1)	Base-emitter saturation voltage	$I_C = 32A$ $I_B = 6.4A$ $I_C = 32A$ $I_B = 6.4A$ $T_j = 100$ °C		1 0.9	1.5 1.5	V V
	di _c /dt	Rate of rise of On-state collector	$V_{CC} = 300V$ $R_{C} = 0$ $t_{p} = 3\mu s$ $I_{B1} = 9.6A$ $T_{j} = 100^{\circ}C$	160	210		A/μs
	V _{CE(3µs)}	Collector-emitter dynamic voltage	$V_{CC} = 300V R_C = 9.3\Omega$ $I_{B1} = 9.6A T_j = 100^{\circ}C$		4.5	8	V
10	V _{CE(5µs)}	Collector-emitter dynamic voltage	$V_{CC} = 300V R_C = 9.3\Omega$ $I_{B1} = 9.6A T_j = 100^{\circ}C$		2.5	4	٧
obsole	t _s t _f t _c	Storage time Fall time Cross-over time	$\begin{split} &I_{C}\!=\!32A & V_{CC}\!=\!50V \\ &V_{BB}\!=\!-5V & R_{BB}\!=\!0.39\Omega \\ &I_{B1}\!=\!6.4A & V_{clamp}\!=\!450V \\ &L\!=\!78\mu H & T_{j}\!=\!100^{\circ} C \end{split}$		3.2 0.25 0.5	4.5 0.4 0.7	μs μs μs
	V _{CEW}	Maximum collector- emitter voltage without snubber	$\begin{split} &I_{CWoff}\!=\!48A & I_{B1}\!=\!6.4A \\ &V_{BB}\!=\!-5V & V_{CC}\!=\!50V \\ &L\!=\!52\mu H & R_{BB}\!=\!0.39\Omega \\ &T_{j}\!=\!125^{\circ}C & \end{split}$	450			V

Note (1) Pulsed duration = $300\mu s$, duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

Figure 2. Thermal impedance

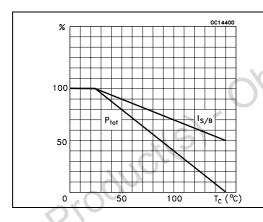


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10⁰ $\delta = 0.5$ $\delta = 0.2$ $\delta = 0.1$ $\delta = 0.1$

Figure 3. Derating curves

Figure 4. Collector-emitter voltage vs base-emitter resistance



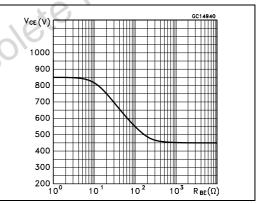
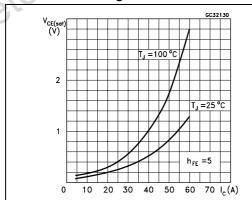
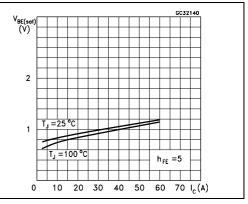


Figure 5. Collector-emitter saturation voltage

Figure 6. Base-emitter saturation voltage

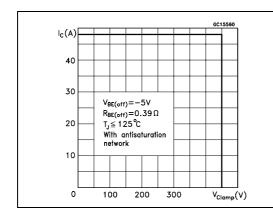




Electrical characteristics BUV298V

Figure 7. Reverse biased SOA

Figure 8. Forward biased SOA



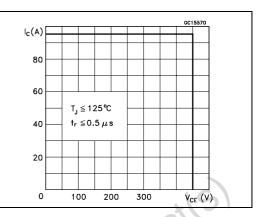
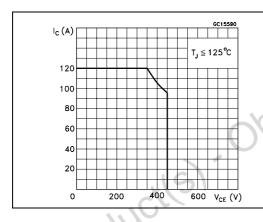


Figure 9. Reverse biased AOA

Figure 10. Forward biased AOA



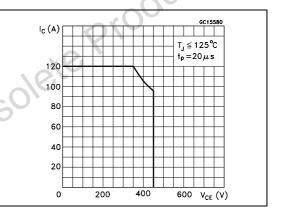
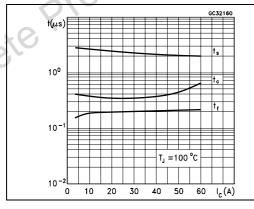
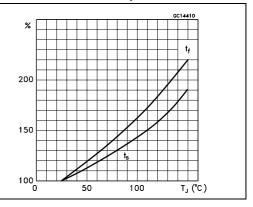


Figure 11. Switching times Inductive load

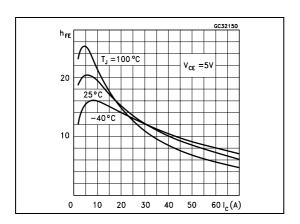
Figure 12. Switching times Inductive load vs temperature





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Figure 13. DC current gain



2.2 Test circuits and waveforms

Figure 14. Turn-on switching test circuit

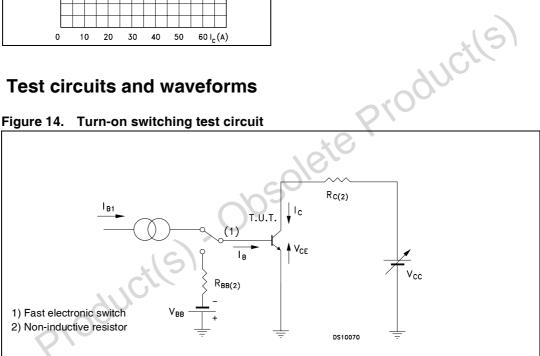
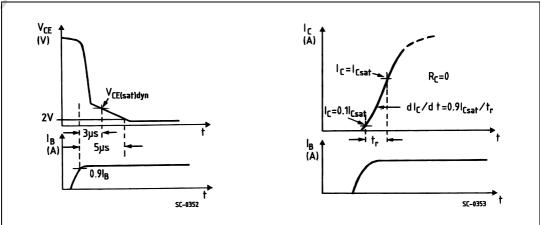


Figure 15. Turn-on switching waveforms



Electrical characteristics BUV298V

Figure 16. Turn-off switching test circuit

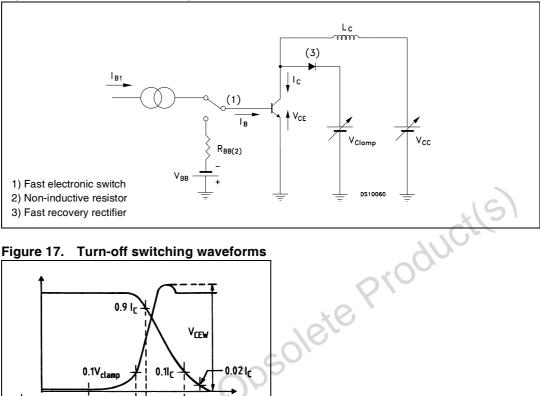
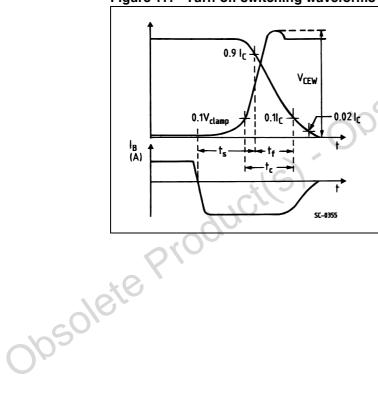


Figure 17. Turn-off switching waveforms



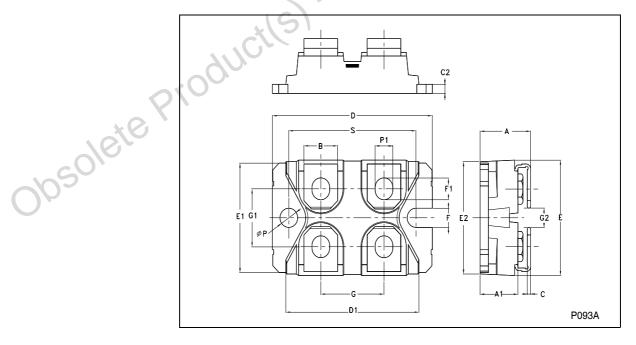
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Obsolete Product(s). Obsolete Product(s)

ISOTOP MECHANICAL DATA

DIM.	mm			inch		
DIN.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	11.8		12.2	0.465		0.480
A1	8.9		9.1	0.350		0.358
В	7.8		8.2	0.307		0.322
С	0.75		0.85	0.029		0.033
C2	1.95		2.05	0.076		0.080
D	37.8		38.2	1.488		1.503
D1	31.5		31.7	1.240	11	1.248
E	25.15		25.5	0.990		1.003
E1	23.85		24.15	0.938	v ()	0.950
E2		24.8			0.976	
G	14.9		15.1	0.586		0.594
G1	12.6		12.8	0.496		0.503
G2	3.5		4.3	0.137		1.169
F	4.1		4.3	0.161		0.169
F1	4.6		5	0.181		0.196
Р	4		4.3	0.157		0.169
P1	4		4.4	0.157		0.173
S	30.1)	30.3	1.185		1.193



BUV298V Revision history

4 Revision history

Table 4. Revision history

Date	Revision	Changes
01-Mar-2003	1	Initial release.
14-Jan-2004	2	Technical migration from ST-press to EDOCS
27-Nov-2006	3	The document has been reformatted

Obsolete Product(s). Obsolete Product(s)

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